3-TERMINAL 0.1A POSITIVE VOLTAGE REGULATORS

This series of fixed-voltage monolithic integrated-circuit voltage regulators is designed for a wide range of applications.

These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation.

In addition, they can be used with power-pass elements to make high current voltage regulators.

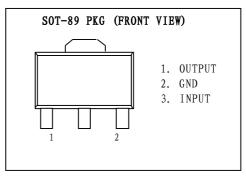
Each of these regulators can deliver up to 100 of output current.

The internal limiting and thermal shutdown features of these regulators make them essentially immune to overload. When used as a replacement for a zener diode-resistor combination, an effective improvement in output impedance can be obtained together with lower-bias current.

FEATURES

- Output Current Up to 100
- ♦ No External Components
- ♦ Internal Thermal Overload Protection
- ♦ Internal Short-Circuit Limiting
- Output Voltage of 5V, 6V, 8V, 9V, 10V, 12V, 15V, 18V and 24V

TO-92 PKG (TOP VIEW) 3. INPUT 2. GND 1-1 1. OUTPUT



ORDERING INFORMATION

Device	Marking	Package
LM78LXX	LM78LXX	TO-92
LM78L05-A/C	LM78L05-A/C	10-92
LM78L05NF	85N	
LM78L05-AF/CF	85A/85C	SOT-89
LM78L06F~24F	806~824	

ABSOLUTE MAXIMUM RATINGS

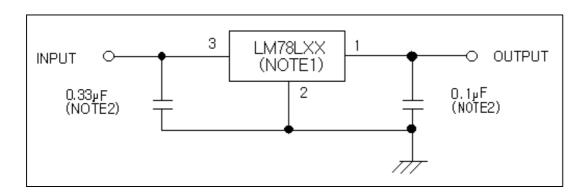
	Characteristic	Symbol	Value	Unit
	LM78L05 /A/C LM78L10		30	
Input voltage	LM78L12 LM78L18	Vı	35	V
	LM78L24		40	
Operating junction temperature		Topr	0 +150	
Storage temperature		Tstg	-65 +150	$^{\circ}$
Soldering temper	erature and time	Tsol	260/10sec	



RECOMMENDED OPERATING CONDITIONS

		Min.	Max.	Unit
	LM78L05 / A / C	7	20	
	LM78L06	8	20	
Input voltage, V⊦	LM78L08	10.5	23	
	LM78L09	11.5	24	
	LM78L10	12.5	25	V
	LM78L12	14.5	27	
	LM78L15	17.5	30	
	LM78L18	20.5	33	
	LM78L24	26.5	39	
Output current,lo			100	
Operating virtual junction temperatu	ıre, Tj	0	125	$^{\circ}\!\mathbb{C}$

TYPICAL APPLICATION



Notes

- 1. To specify an output voltage, substitute voltage for "XX"
- 2. Bypass capacitors are recommended for optimum stability and transient response and should be located as close as possible to the regulators.



LM78L05 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, Vi=10V, Io=40 (unless otherwise noted)

Characteistic	Symbol	Test condi	tion *	Min.	Тур.	Max.	Unit
			25℃	4.8	5	5.2	
Output voltage **	Vоит	1 ≤ Io ≤ 40	0°C 125°C	4.75	5	5.25	٧
		7V ≤ Vı ≤ 20V					
		1 ≤ Io ≤ 70		4.75	5	5.25	
Line regulation	Reg line	7V ≤ V₁ ≤ 20V	25℃		32	150	
		8V ≤ V₁ ≤ 20V			26	100	
Load regulation	Reg load	1 ≤ Io ≤ 100	25℃		15	60	
		1 ≤ Io ≤ 40			8	30	
Bias current	Ів		25℃		3.8	6	
			125℃			5.5	
Bias current change	△ I B	9V ≤ V₁ ≤ 20V	0°C 125°C			1.5	
, and the second		1 ≤ lo ≤ 40				0.1	
Output noise voltage	Vn	10Hz ≤ f ≤ 100kHz	25℃		42		
Ripple rejection	RR	8V ≤ V₁ ≤ 18V	25℃	41	49		
Tappio rojostion	1.01	f=120Hz	200	r I	10		
Dropout voltage	VD		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a 0.33 capacitor across the input and a 0.1 capacitor across the output.



LM78L05A ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, V_I=10V, I_O=40 (unless otherwise noted)

Characteistic	Symbol	Test condi	ition *	Min.	Тур.	Max.	Unit
			25℃	4.9	5	5.1	
Output voltage **	Vоит	1 ≤ Io ≤ 40	0℃ 125℃	4.9	5	5.1	V
		7V ≤ Vı ≤ 20V					
		1 ≤ lo ≤ 70		4.9	5	5.1	
Line regulation	Reg line	7V ≤ V₁ ≤ 20V	25℃		5	50	
		8V ≤ V₁ ≤ 20V			3	25	
_oad regulation	Reg load	1 ≤ Io ≤ 100	25℃		15	60	
		1 ≤ Io ≤ 40			8	30	
Bias current	Ів		25℃		3.8	6	
			125℃			5.5	
Bias current change	△ I B	9V ≤ V₁ ≤ 20V	0°C 125°C			1.5	
		1 ≤ Io ≤ 40				0.1	
Output noise voltage	Vn	10Hz ≤ f ≤ 100kHz	25℃		42		
Ripple rejection	RR	8V ≤ V₁ ≤ 18V	25℃	41	49		
16.5.3		f=120Hz					
Dropout voltage	VD		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a 0.33 capacitor across the input and a 0.1 capacitor across the output.



LM78L05C ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, Vi=10V, Io=40 (unless otherwise noted)

Characteistic	Symbol	Test condi	tion *	Min.	Тур.	Max.	Unit
			25℃	4.95	5	5.05	
Output voltage **	Vоит	1 ≤ Io ≤ 40	0℃ 125℃	4.95	5	5.05	V
		7V ≤ Vı ≤ 20V					
		1 ≤ Io ≤ 70		4.95	5	5.05	
Line regulation	Reg line	7V ≤ V₁ ≤ 20V	25℃		5	50	
		8V ≤ V₁ ≤ 20V			3	25	
Load regulation	Reg load	1 ≤ Io ≤ 100	25℃		15	50	
		1 ≤ Io ≤ 40			8	25	
Bias current	lв		25℃		3.8	6	
			125℃			5.5	
Bias current change	Δl _B	9V ≤ V₁ ≤ 20V	0°C 125°C			1.5	
		1 ≤ Io ≤ 40				0.1	
Output noise voltage	Vn	10Hz ≤ f ≤ 100kHz	25℃		42		
Ripple rejection	RR	8V ≤ V₁ ≤ 18V	25℃	41	49		
li bira i altana		f=120Hz		• •			
Dropout voltage	V _D	1 120112	25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a 0.33 capacitor across the input and a 0.1 capacitor across the output.



LM78L06 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, Vi=10V, Io=40 (unless otherwise noted)

Characteistic	Symbol	Test condi	tion *	Min.	Тур.	Max.	Unit
			25℃	5.75	6	6.25	
Output voltage **	Vоит	1 ≤ Io ≤ 40	0℃ 125℃	5.7	6	6.3	V
		8V ≤ V₁ ≤ 20V					
		1 ≤ Io ≤ 70		5.7	6	6.3	
Line regulation	Reg line	8V ≤ V₁ ≤ 20V	25℃		35	175	
		9V ≤ V₁ ≤ 20V			29	125	
Load regulation	Reg load	1 ≤ Io ≤ 100	25℃		16	80	
		1 ≤ Io ≤ 40			9	40	
Bias current	lв		25℃		3.9	6	
			125℃			5.5	
Bias current change	△ I B	9V ≤ V₁ ≤ 20V	0°C 125°C			1.5	
		1 ≤ Io ≤ 40				0.1	
Output noise voltage	Vn	10Hz ≤ f ≤ 100kHz	25℃		46		
Ripple rejection	RR	9V ≤ V₁ ≤ 19V	25℃	40	48		
,, -,,		f=120Hz		-			
Dropout voltage	V _D	1 123112	25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a 0.33 capacitor across the input and a 0.1 capacitor across the output.



LM78L08 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, V_i=14V, I_o=40 (unless otherwise noted)

Characteistic	Symbol	Test condi	tion *	Min.	Тур.	Max.	Unit
			25℃	7.7	8	8.3	
Output voltage **	Vоит	1 ≤ Io ≤ 40	0℃ 125℃	7.6	8	8.4	V
		10.5V ≤ V₁ ≤ 23V					
		1 ≤ Io ≤ 70		7.6	8	8.4	
Line regulation	Reg line	10.5V ≤ V₁ ≤ 23V	25℃		42	175	
		11V ≤ V₁ ≤ 23V			36	125	
Load regulation	Reg load	1 ≤ Io ≤ 100	25℃		18	80	
		1 ≤ Io ≤ 40			10	40	
Bias current	Ів		25℃		4	6	
			125℃			5.5	
Bias current change	Δl _B	11V ≤ V₁ ≤ 23V	0℃ 125℃			1.5	
		1 ≤ Io ≤ 40				0.1	
Output noise voltage	Vn	10Hz ≤ f ≤ 100kHz	25℃		54		
Ripple rejection	RR	13V ≤ V₁ ≤ 23V	25℃	37	46		
•		f=120Hz					
Dropout voltage	VD		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a 0.33 capacitor across the input and a 0.1 capacitor across the output.



LM78L09 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, Vi=16V, Io=40 (unless otherwise noted)

Characteistic	Symbol	Test condi	tion *	Min.	Тур.	Max.	Unit
			25℃	8.6	9	9.4	
Output voltage **	Vоит	1 ≤ Io ≤ 40	0°C 125°C	8.55	9	9.45	V
		12V ≤ V₁ ≤ 24V					
		1 ≤ lo ≤ 70		8.55	9	9.45	
Line regulation	Reg line	12V ≤ V₁ ≤ 24V	25℃		45	175	
		13V ≤ V₁ ≤ 24V			40	125	
Load regulation	Reg load	1 ≤ Io ≤ 100	25℃		19	90	
		1 ≤ Io ≤ 40			11	40	
Bias current	lв		25℃		4.1	6	
			125℃			5.5	
Bias current change	△ I B	13V ≤ V₁ ≤ 24V	0℃ 125℃			1.5	
-		1 ≤ Io ≤ 40				0.1	
Output noise voltage	Vn	10Hz ≤ f ≤ 100kHz	25℃		58		
Ripple rejection	RR	13V ≤ V₁ ≤ 23V	25℃	38	45		
11		f=120Hz					
Dropout voltage	VD		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a 0.33 capacitor across the input and a 0.1 capacitor across the output.



LM78L10 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, Vi=17V, Io=40 (unless otherwise noted)

Characteistic	Symbol	Test condi	tion *	Min.	Тур.	Max.	Unit
			25℃	9.6	10	10.4	
Output voltage **	Vоит	1 ≤ Io ≤ 40	0°C 125°C	9.5	10	10.5	V
		13V ≤ V₁ ≤ 25V					
		1 ≤ lo ≤ 70		9.5	10	10.5	
Line regulation	Reg line	13V ≤ V₁ ≤ 25V	25℃		51	175	
		14V ≤ V₁ ≤ 25V			42	125	
Load regulation	Reg load	1 ≤ Io ≤ 100	25℃		20	90	
		1 ≤ Io ≤ 40			11	40	
Bias current	lв		25℃		4.2	6	
			125℃			5.5	
Bias current change	△ I B	14V ≤ V₁ ≤ 25V	0℃ 125℃			1.5	
-		1 ≤ Io ≤ 40				0.1	
Output noise voltage	Vn	10Hz ≤ f ≤ 100kHz	25℃		62		
Ripple rejection	RR	15V ≤ V₁ ≤ 25V	25℃	37	44		
,,,		f=120Hz		-			
Dropout voltage	V _D	. 123112	25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a 0.33 capacitor across the input and a 0.1 capacitor across the output.



LM78L12 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, Vi=19V, Io=40 (unless otherwise noted)

Characteistic	Symbol	Test condi	ition *	Min.	Тур.	Max.	Unit
			25℃	11.5	12	12.5	
Output voltage **	Vоит	1 ≤ Io ≤ 40	0℃ 125℃	11.4	12	12.6	V
		14V ≤ V₁ ≤ 27V					
		1 ≤ Io ≤ 70		11.4	12	12.6	
Line regulation	Reg line	14.5V ≤ V₁ ≤ 27V	25℃		55	250	
		16V ≤ V₁ ≤ 27V			49	200	
Load regulation	Reg load	1 ≤ I ₀ ≤ 100	25℃		22	100	
		1 ≤ Io ≤ 40			13	50	
Bias current	Ів		25℃		4.3	6.5	
			125℃			6	
Bias current change	Δl _B	16V ≤ V₁ ≤ 27V	0℃ 125℃			1.5	
		1 ≤ Io ≤ 40				0.1	
Output noise voltage	Vn	10Hz ≤ f ≤ 100kHz	25℃		70		
Ripple rejection	RR	15V ≤ V₁ ≤ 25V	25℃	37	42		
		f=120Hz					
Dropout voltage	V _D		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a 0.33 capacitor across the input and a 0.1 capacitor across the output.

